

Physics underlying QD laser behaviors

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Lasers

Quantum optics

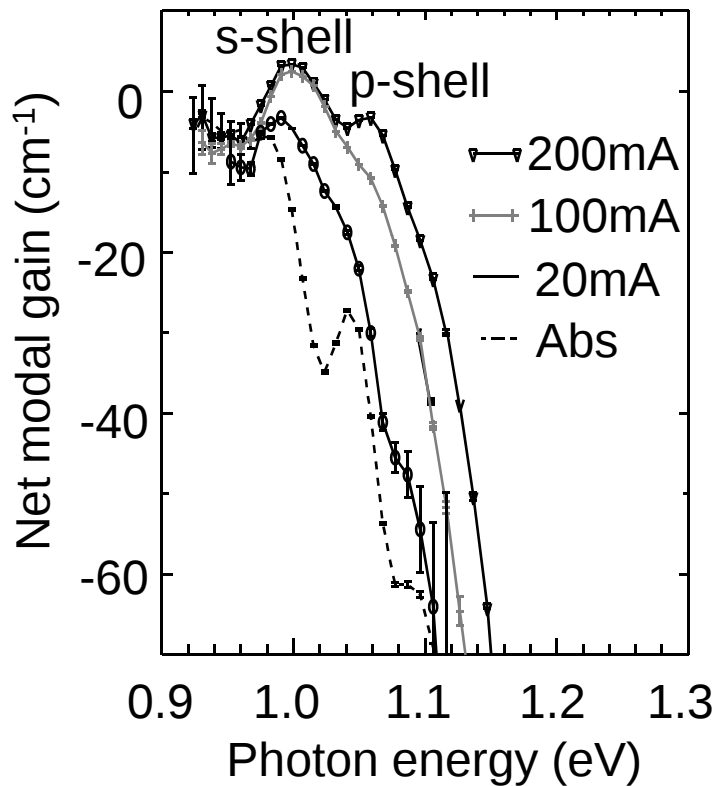
Experiment

Work was performed at Sandia's Solid-State Lighting Science Center, an Energy Frontier Research Center (EFRC) funded by the U. S. Department of Energy, Office of Science, Office of Basic Energy Sciences. Sandia National Laboratories is a multi-program laboratory operated by Sandia Corporation, a wholly owned subsidiary of Lockheed Martin company, for the U.S. Department of Energy's National Nuclear Security Administration under contract DE-AC04-94AL85000."

Quantum-dot absorption/gain spectra

Experiment

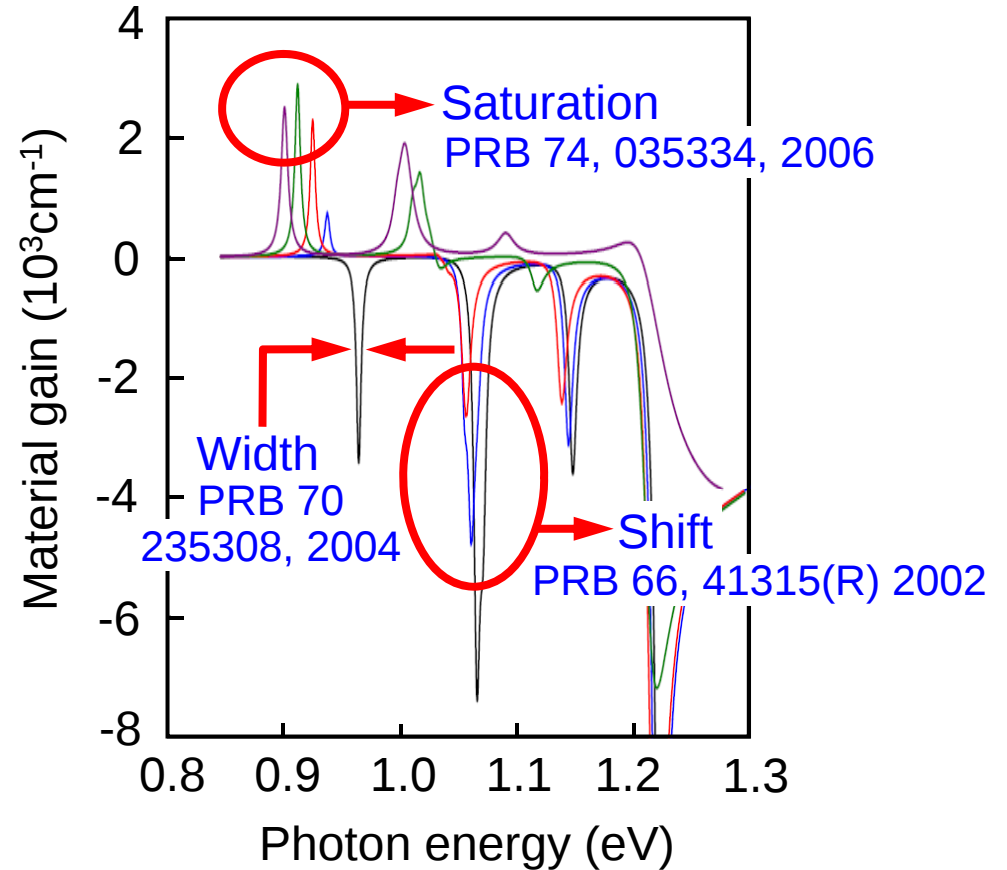
(Inhomogeneously broadened)



(measured at Cardiff University)

Calculation

(Intrinsic)



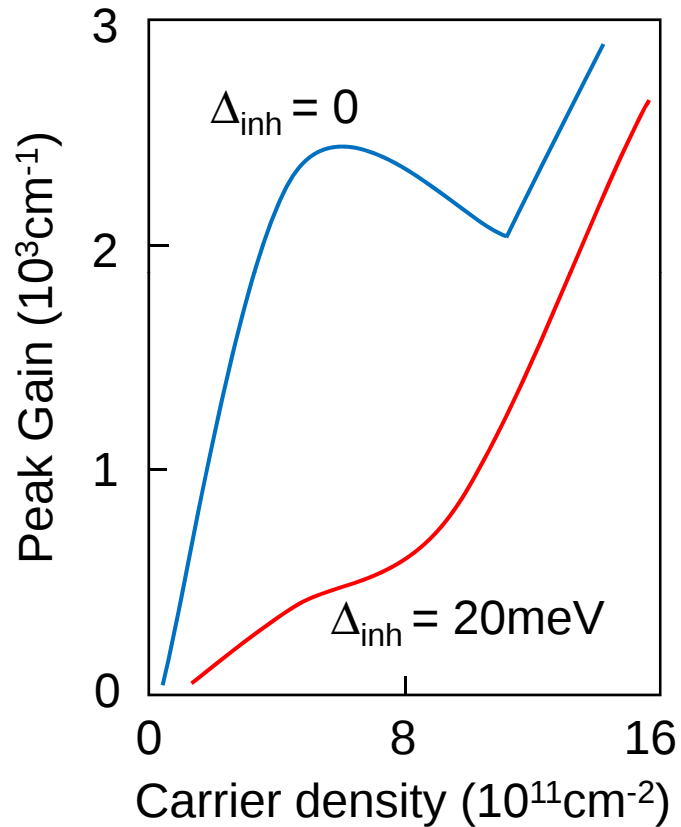
$$N_{\text{dot}} = 2 \times 10^{11} \text{cm}^{-2}, T = 300 \text{K}$$

$$N = 0.1x, 0.5x, 1x, 2x, 3x 10^{12} \text{cm}^{-2}$$

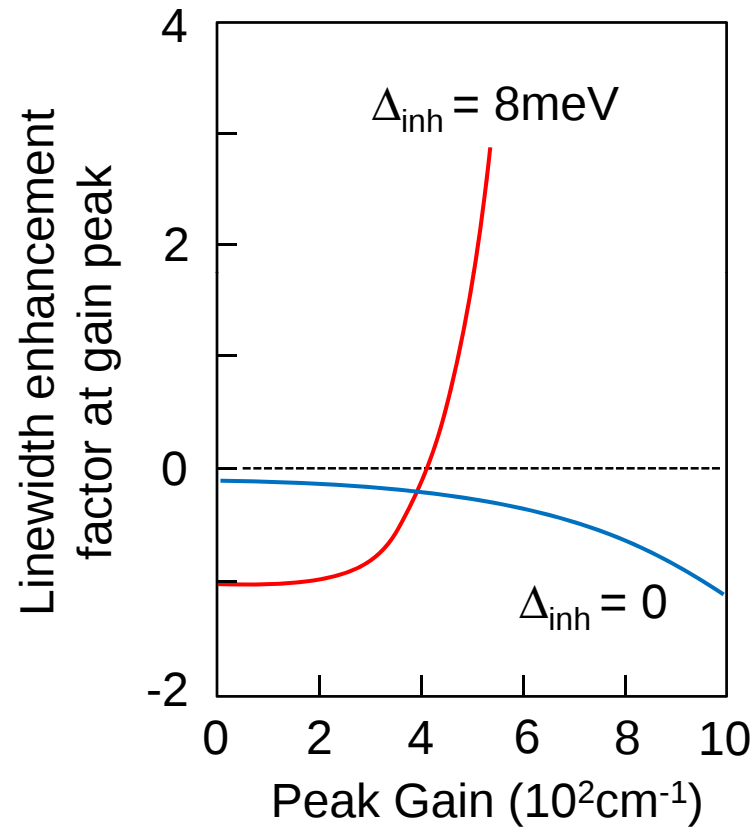
Relevance to laser operation

InGaAs QD, 300K, $N_{\text{dot}}=5 \times 10^{10} \text{cm}^{-2}$

Gain saturation



Carrier-induced refractive index

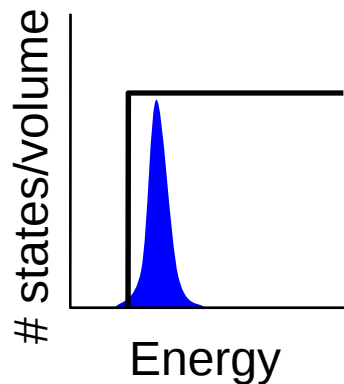
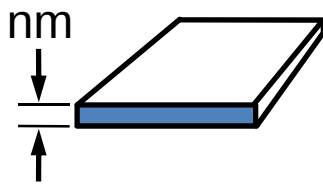


Underlying physics

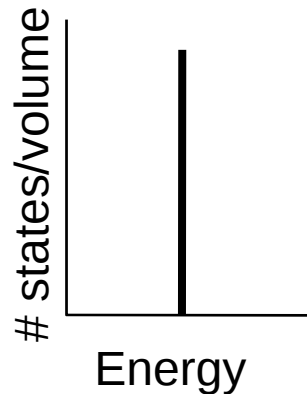
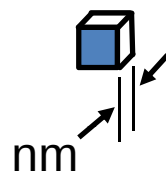
Free-Carrier effects

(Density of states)

Quantum well



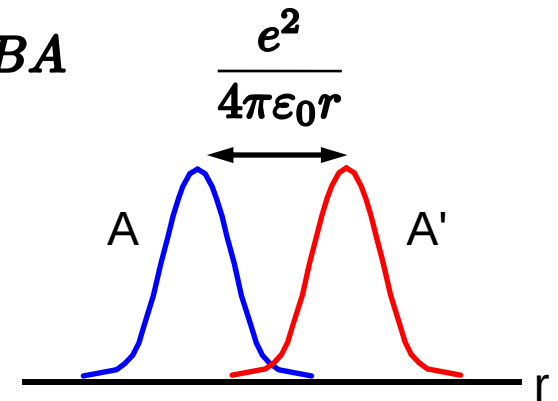
Quantum dot



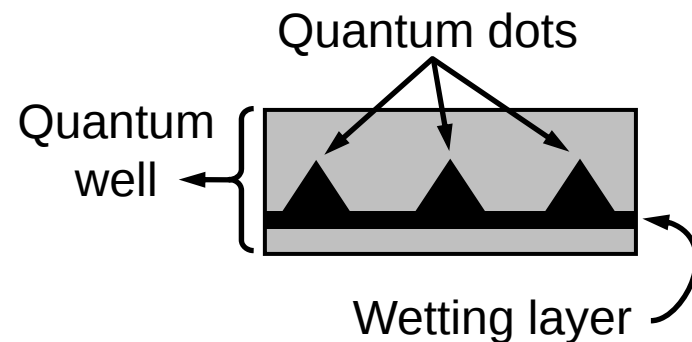
Many-body effects

(Quantum statistics + Coulomb interaction)

$$\{A, B\} = AB + BA$$



Active region



Strong influence from wells

Schneider, Chow, Koch, PRB **64**, 115315, 2001

Many-body effects

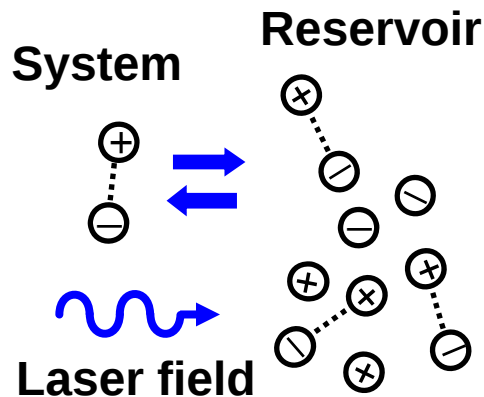
Hartree-Fock (mean field)

Bandgap renormalization
Exciton/Coulomb Enhancement

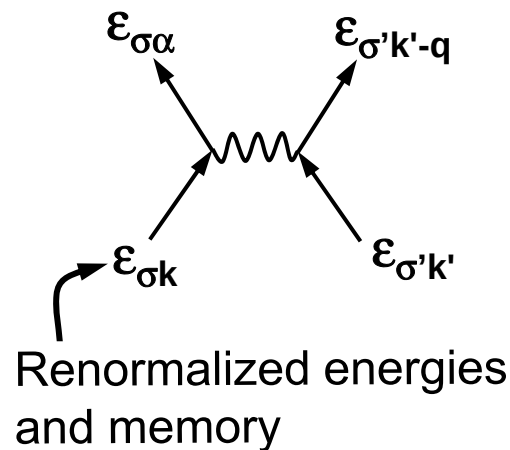
Correlations

Relaxation, dephasing
and screening

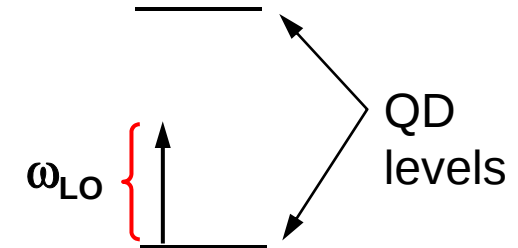
System is its own reservoir



Carrier-carrier scattering



Polarons



$$\left. \frac{\partial p_k}{\partial t} \right|_{col} = \underbrace{-\sigma_k^d p_k}_{\text{Diagonal}} + \underbrace{\sum_k \sigma_{k,k'}^{nd} p_{k'}}_{\text{Nondiagonal dephasing}}$$

Nondiagonal dephasing

Non perturbative carrier-phonon
description for correct estimation
of phonon bottleneck problem

Hamiltonian

$$H = \sum_n \epsilon_n a_n^\dagger a_n + \sum_m \epsilon_m b_m^\dagger b_m \quad \text{Single-particle}$$

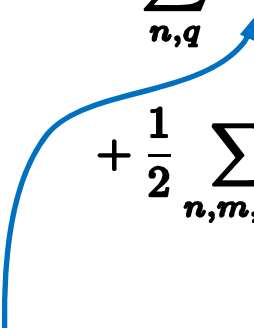
$$- \sum_{n,m} (\mu_{nm} a_n^\dagger b_m^\dagger + \mu_{nm}^* b_m a_n) E(z, t) \quad \text{Light-matter}$$

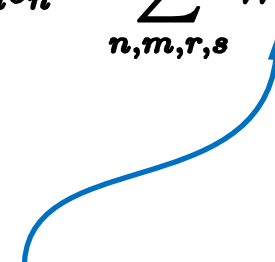
$$+ \sum_{n,q} \hbar G_q a_{n+q}^\dagger a_n (b_q + b_{-q}^\dagger) \quad \text{Carrier - phonon}$$

$$+ \frac{1}{2} \sum_{n,m,r,s} W_{nm}^{rs} a_r^\dagger a_s^\dagger a_m a_n + \frac{1}{2} \sum_{n,m,r,s} W_{nm}^{rs} b_r^\dagger b_s^\dagger b_m b_n - \sum_{n,m,r,s} W_{nm}^{rs} a_r^\dagger b_s^\dagger b_m a_n$$

Carrier – carrier

Fröhlich electron-LO
phonon coupling

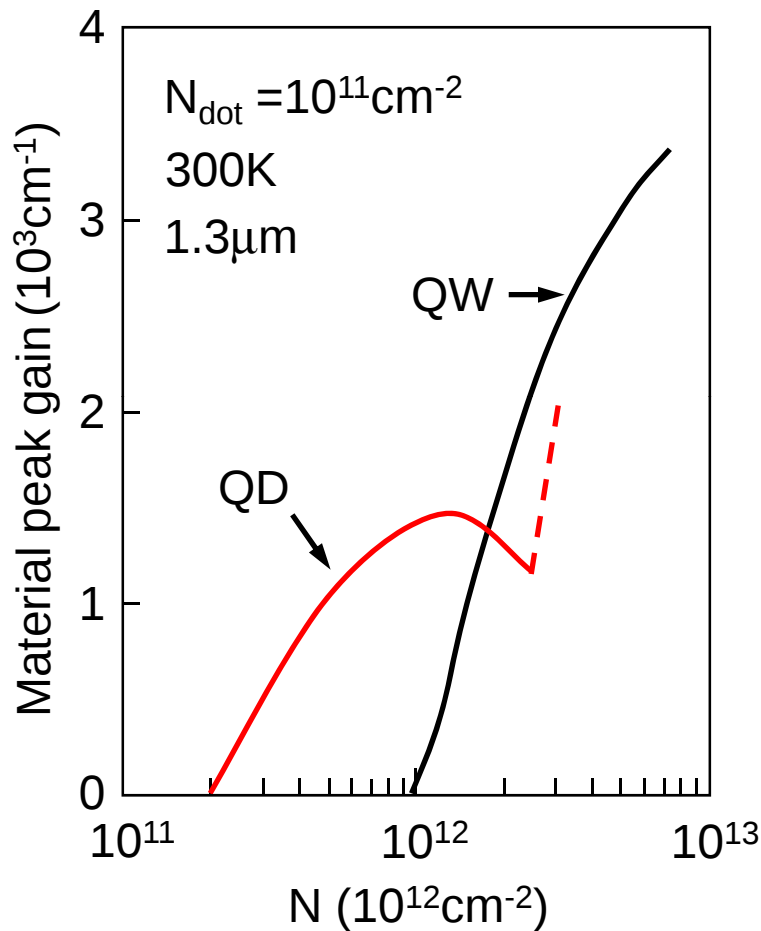




$$\int d^3r \, d^3r' \phi_r^*(r) \phi_s^*(r') \frac{e^2}{4\pi\epsilon_b |r - r'|} \phi_m(r') \phi_n(r)$$

Quantum dot / quantum well comparison

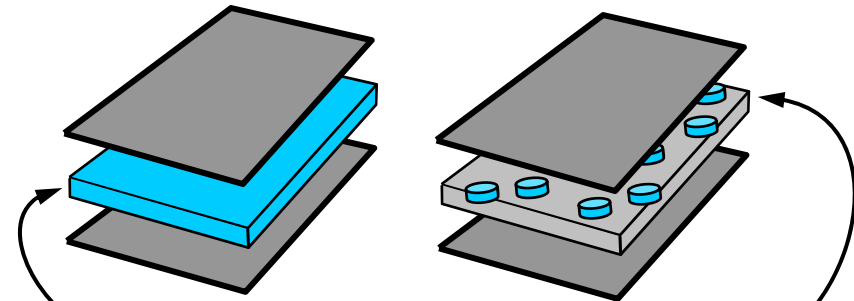
Intrinsic



Unambiguous scaling of the axii
by eliminating dephasing rate as
free parameter

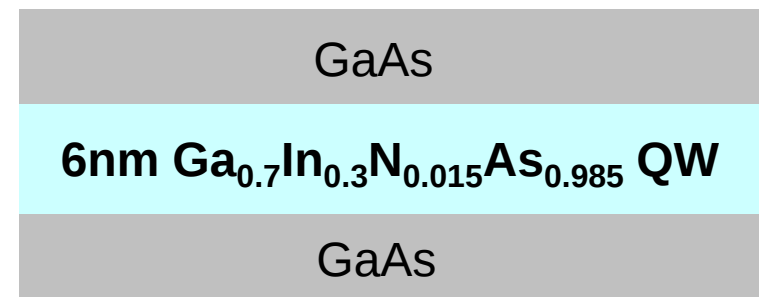
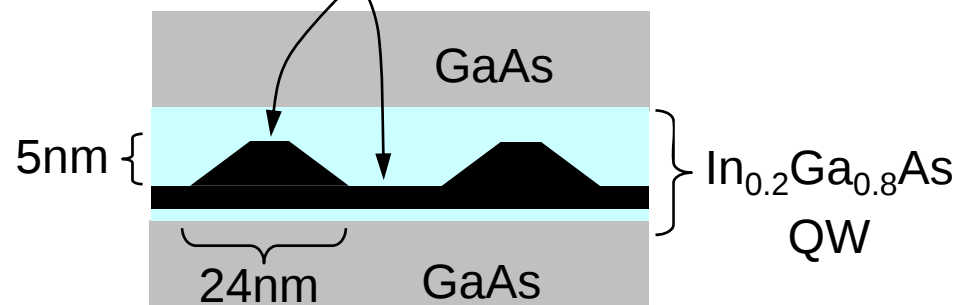
Quantum well

Quantum dot



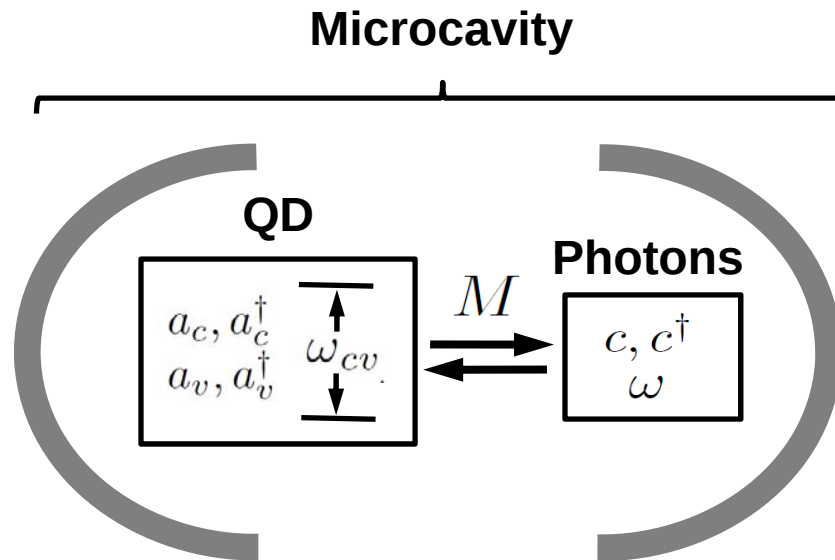
Material gain/active region

InAs QDs and wetting layer



Quantum-dot cavity-quantum-electrodynamics (QD-CQED)

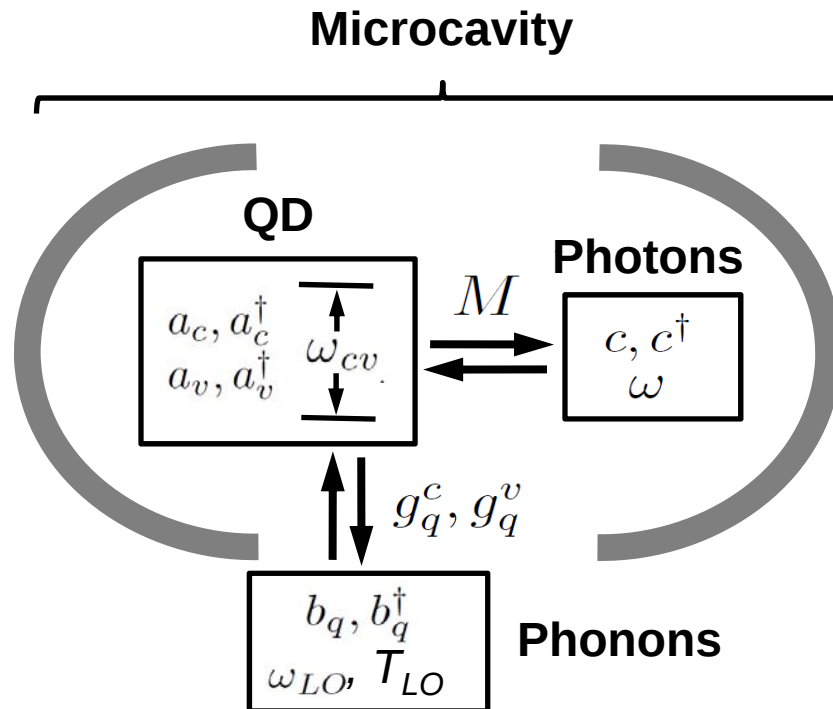
Single electron in quantum dot interacting with microcavity field



Control of spontaneous emission

Quantum-dot cavity-quantum-electrodynamics (QD-CQED)

Single electron in quantum dot interacting with microcavity field + phonon bath



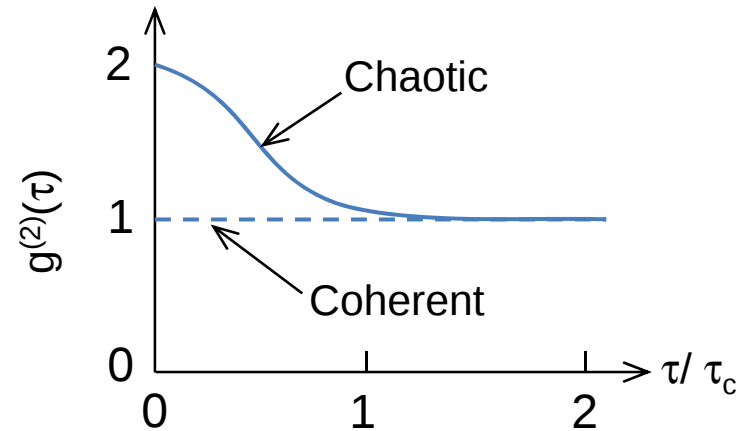
Control of spontaneous emission

Modification of photon statistics

2nd-order correlation function

$$g^{(2)}(\tau) = \frac{\langle I(t) I(t + \tau) \rangle}{\langle I(t) \rangle^2}$$

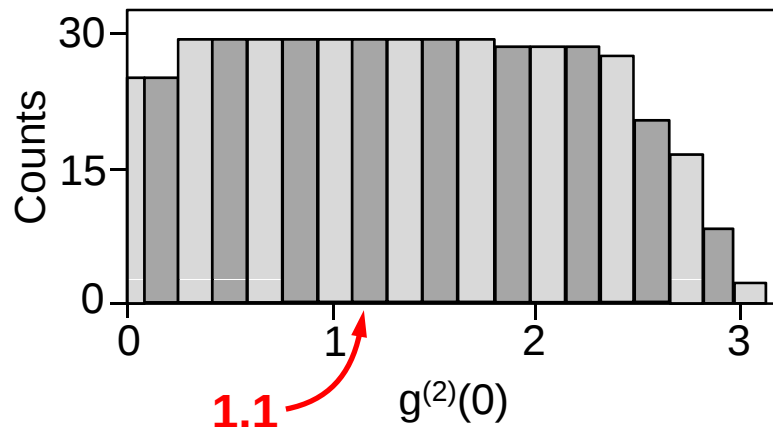
$$= \frac{\langle c^\dagger(t) c^\dagger(t + \tau) c(t + \tau) c(t) \rangle}{\langle c^\dagger(t) c(t) \rangle \langle c^\dagger(t + \tau) c(t + \tau) \rangle}$$



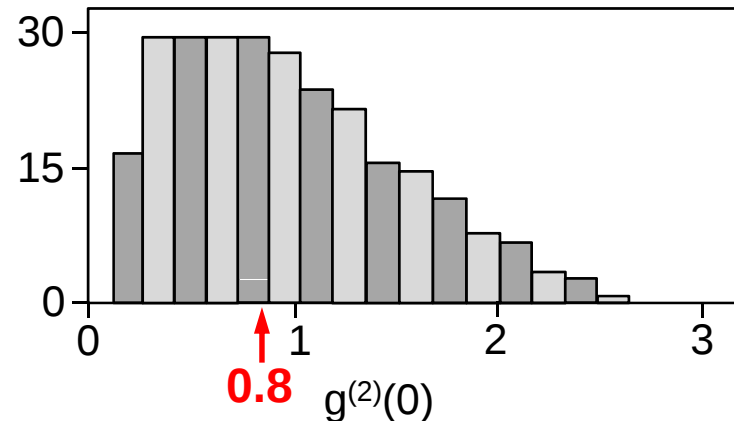
- • • • • $g(0) > 1$ Bunched light
- • • • • $g(0) = 1$ Coherent light (random)
- • • • • $g(0) < 1$ Antibunched light

Start with thermal state

3K phonon bath



300K phonon bath

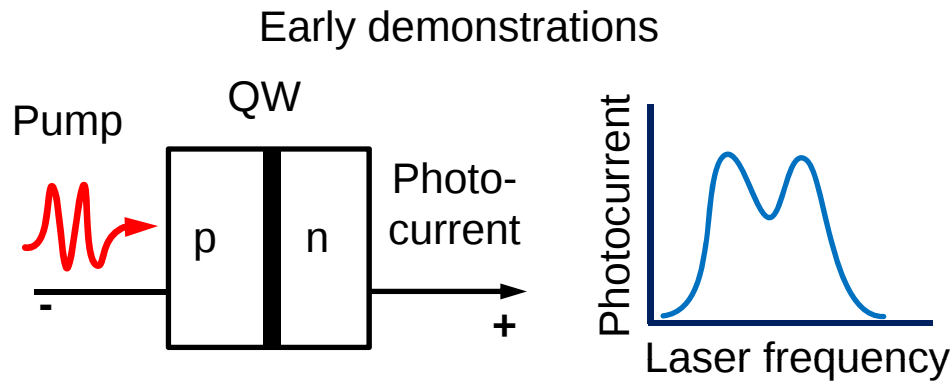


Carmelet, Richter, Chow and Knorr, PRL **104**, 156801 (2010)

Experiments

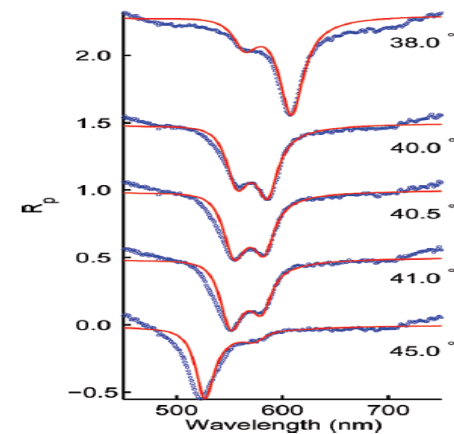
First step is demonstration of strong light-matter interaction

Optically pump



Reithmaier et al., Nature **432**, 197 (2004) and others

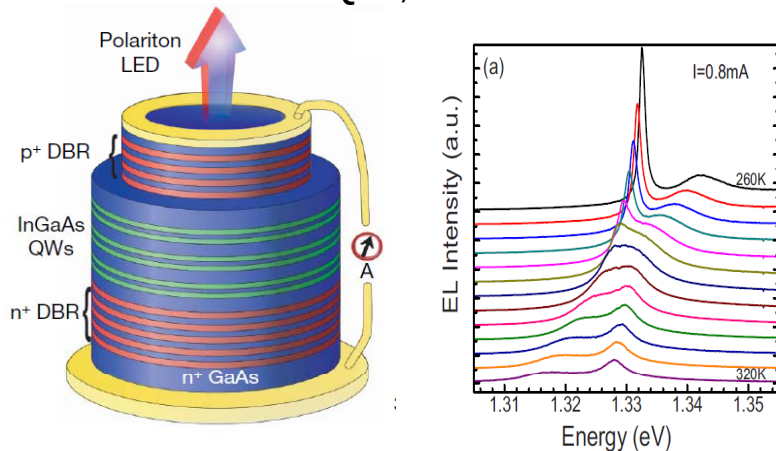
Plasmon mediated



Gomez et al., Nano Lett. **10**, 274 (2010)

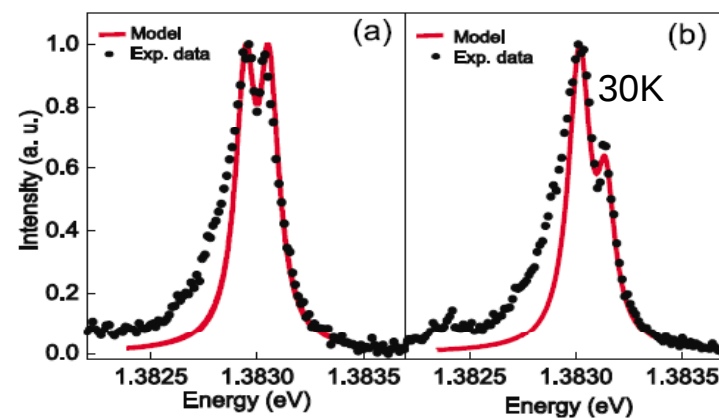
Electrically pump

QW, 300K



Tsintzos et al., Nature Lett. **453** 373 (2008)
APL **94**, 071109 (2009)

Quantum dots

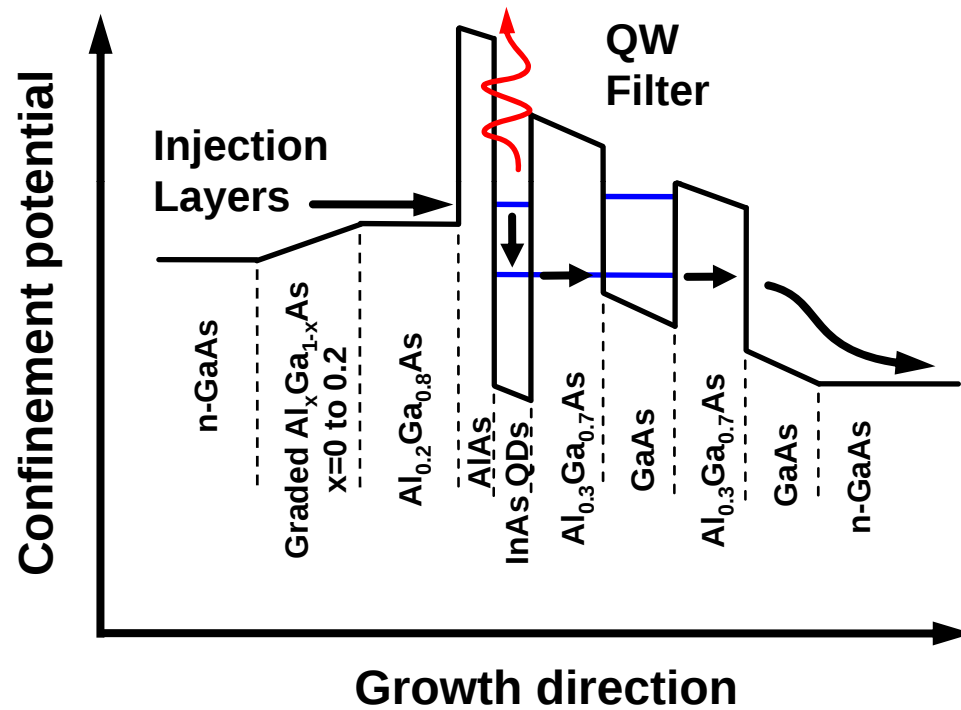


Kistner et al., APL **96**, 221102 (2010)

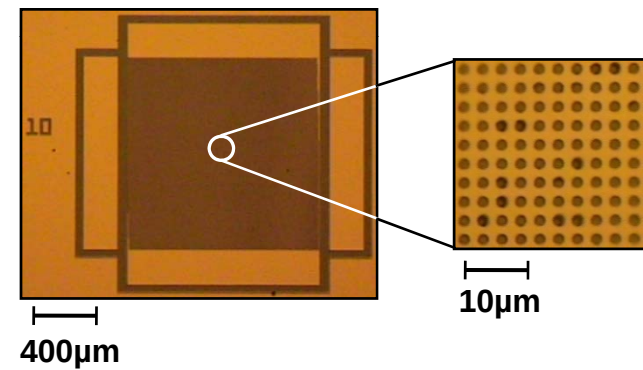
Experiments

Mid-IR emitter using inter-conduction-state transition in InAs quantum dots

(Sandia/U. Mass./Princeton)



Hole array and electrical contact



Observation of strong light-matter interaction in electrically-excited InAs quantum dots (Sandia/U. Mass./Princeton)

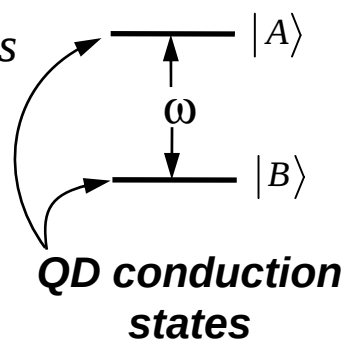
Rabi frequency

$$\Omega_R = \frac{e \times 10 \text{ nm} \times 3 \text{ KV/cm}}{\hbar} = 4.7 \times 10^{12} \text{ s}^{-1}$$

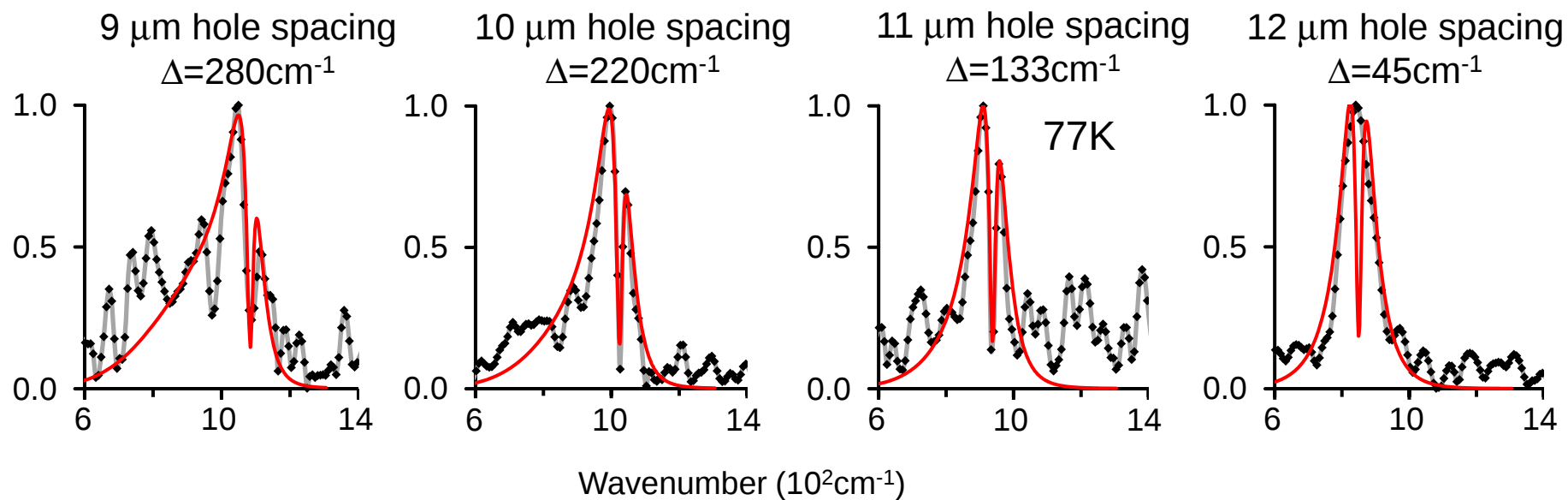
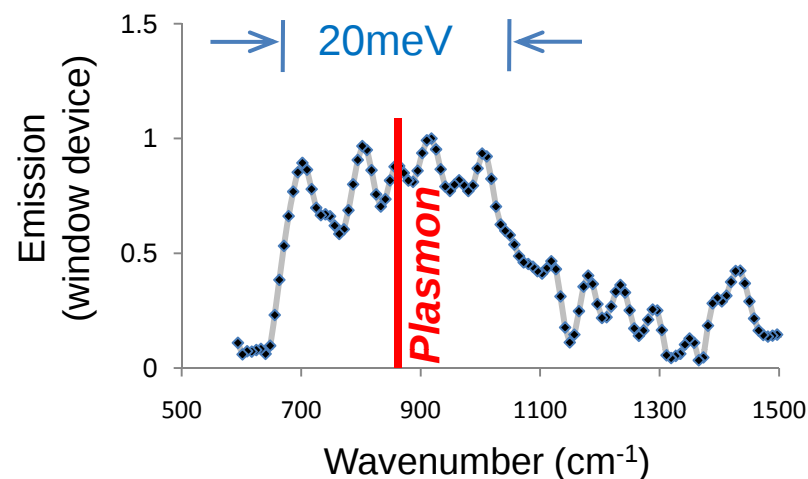
$7 \times 10^8 \text{ photons}$

Dephasing

$$\gamma = 1.26 \times 10^{12} \text{ s}^{-1}$$



Inhomogeneous broadening



Physics underlying QD laser behaviors

Lasers

Intrinsic laser properties determined by Coulomb correlations

Quantum optics

Control of photon statistics

Experiment

Strong light-matter interaction possible at high temperature
and with current injection

Collaborators

Lasers: Frank Jahnke and Michael Lorke (University of Bremen)

Quantum optics: Alexander Carmele and Andreas Knorr (Technical University, Berlin)

Experiment: Eric Shaner and Brandon Passmore (Sandia), Dan Wasserman (U. Massachusetts), Stephen Lyon (Princeton)